

INTERNATIONAL GEMOLOGICAL INSTITUTE

LABORATORY GROWN DIAMOND REPORT

IGI LABORATORY GROWN DIAMOND IDENTIFICATION REPORT

March 9, 2023	
IGI Report Number	LG572352412
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	4.60 - 4.62 X 2.89 MM
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GRADING RESULTS

Carat Weight	0.38 CARAT
Color Grade	E
Clarity Grade	VS 1
Cut Grade	EXCELLENT

ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	1G572352412

Comments: As Grown - No indication of post-growth treatment. This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

LG572352412





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